

## Three Phase Bridge (Power Modules), 90/110 A


**MTK**

### FEATURES

- Package fully compatible with the industry standard INT-A-PAK power modules series
- High thermal conductivity package, electrically insulated case
- Excellent power volume ratio, outline for easy connections to power transistor and IGBT modules
- 4000 V<sub>RMS</sub> isolating voltage
- UL E78996 approved
- Totally lead (Pb)-free
- Designed and qualified for industrial level



### DESCRIPTION

<b>PRODUCT SUMMARY</b>	
I <sub>O</sub>	90/110 A

A range of extremely compact, encapsulated three phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and heavy duty applications.

<b>MAJOR RATINGS AND CHARACTERISTICS</b>				
SYMBOL	CHARACTERISTICS	90MT.K	110MT.K	UNITS
I <sub>O</sub>		90 (120)	110 (150)	A
	T <sub>C</sub>	90 (61)	90 (57)	°C
I <sub>FSM</sub>	50 Hz	770	950	A
	60 Hz	810	1000	
I <sup>2</sup> t	50 Hz	3000	4500	A <sup>2</sup> s
	60 Hz	2700	4100	
I <sup>2</sup> \t		30 000	45 000	A <sup>2</sup> \s
V <sub>RRM</sub>	Range	800 to 1600		V
T <sub>Stg</sub>	Range	- 40 to 150		°C
T <sub>J</sub>				

### ELECTRICAL SPECIFICATIONS

<b>VOLTAGE RATINGS</b>				
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = MAXIMUM mA
90-110MT..K	80	800	900	10
	100	1000	1100	
	120	1200	1300	
	140	1400	1500	
	160	1600	1700	

# 90-110MT.KPbF Series

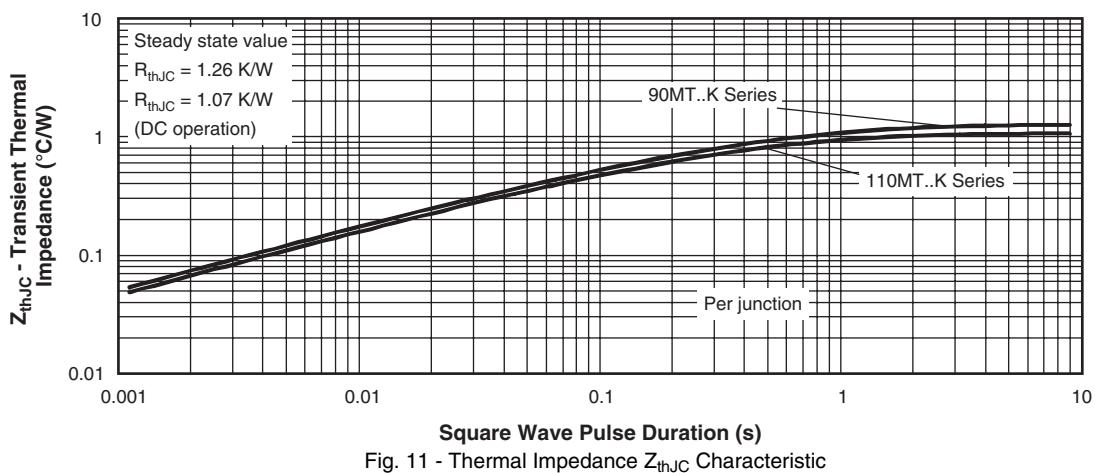
Vishay High Power Products

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(Power Modules), 90/110 A



FORWARD CONDUCTION										
PARAMETER	SYMBOL	TEST CONDITIONS			90MT.K	110MT.K	UNITS			
Maximum DC output current at case temperature	$I_O$	120° rect. conduction angle			90 (120)	110 (150)	A			
					90 (61)	90 (57)	°C			
Maximum peak, one-cycle forward, non-repetitive surge current	$I_{FSM}$	$t = 10 \text{ ms}$	No voltage reapplied	Initial $T_J = T_J \text{ maximum}$	770	950	A			
		$t = 8.3 \text{ ms}$	100 % $V_{RRM}$ reapplied		810	1000				
		$t = 10 \text{ ms}$			650	800				
		$t = 8.3 \text{ ms}$	100 % $V_{RRM}$ reapplied		680	840				
Maximum $I^2t$ for fusing	$I^2t$	$t = 10 \text{ ms}$	No voltage reapplied	Initial $T_J = T_J \text{ maximum}$	3000	4500	$\text{A}^2\text{s}$			
		$t = 8.3 \text{ ms}$	100 % $V_{RRM}$ reapplied		2700	4100				
		$t = 10 \text{ ms}$			2100	3200				
		$t = 8.3 \text{ ms}$			1900	2900				
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1 \text{ to } 10 \text{ ms}$ , no voltage reapplied			30 000	45 000	$\text{A}^2\sqrt{\text{s}}$			
Low level value of threshold voltage	$V_{F(TO)1}$	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J$ maximum			0.89	0.81	V			
High level value of threshold voltage	$V_{F(TO)2}$	$(I > \pi \times I_{F(AV)})$ , $T_J$ maximum			1.05	0.99				
Low level value of forward slope resistance	$r_{f1}$	$(16.7 \% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J$ maximum			5.11	4.37	$\text{m}\Omega$			
High level value of forward slope resistance	$r_{f2}$	$(I > \pi \times I_{F(AV)})$ , $T_J$ maximum			4.64					
Maximum forward voltage drop	$V_{FM}$	$I_{pk} = 150 \text{ A}$ , $T_J = 25 \text{ °C}$ $t_p = 400 \mu\text{s}$ single junction			1.6	1.4	V			
RMS isolation voltage	$V_{ISOL}$	$T_J = 25 \text{ °C}$ , all terminal shorted $f = 50 \text{ Hz}$ , $t = 1 \text{ s}$			4000					

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS			90MT.K	110MT.K	UNITS
Maximum junction operating and storage temperature range	$T_J$ , $T_{Stg}$				- 40 to 150		°C
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation per module			0.21	0.18	°C/W
		DC operation per junction			1.26	1.07	
		120° rect. conduction angle per module			0.25	0.21	
		120° rect. conduction angle per junction			1.47	1.25	
Maximum thermal resistance, case to heatsink per module	$R_{thCS}$	Mounting surface smooth, flat and greased			0.03		
Mounting torque $\pm 10 \%$	to heatsink to terminal	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.			4 to 6	Nm	
					3 to 4		
Approximate weight					176	g	


 Fig. 11 - Thermal Impedance  $Z_{thJC}$  Characteristic

## ORDERING INFORMATION TABLE

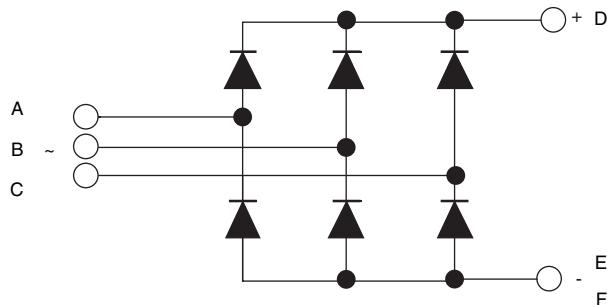
Device code	11	0	MT	160	K	PbF
	(1)	(2)	(3)	(4)	(5)	

- [1] - Current rating code: 9 = 90 A (average)  
11 = 110 A (average)
- [2] - Three phase diodes bridge
- [3] - Essential part number
- [4] - Voltage code x 10 =  $V_{RRM}$  (see Voltage Ratings table)
- [5] - PbF = Lead (Pb)-free

### Note

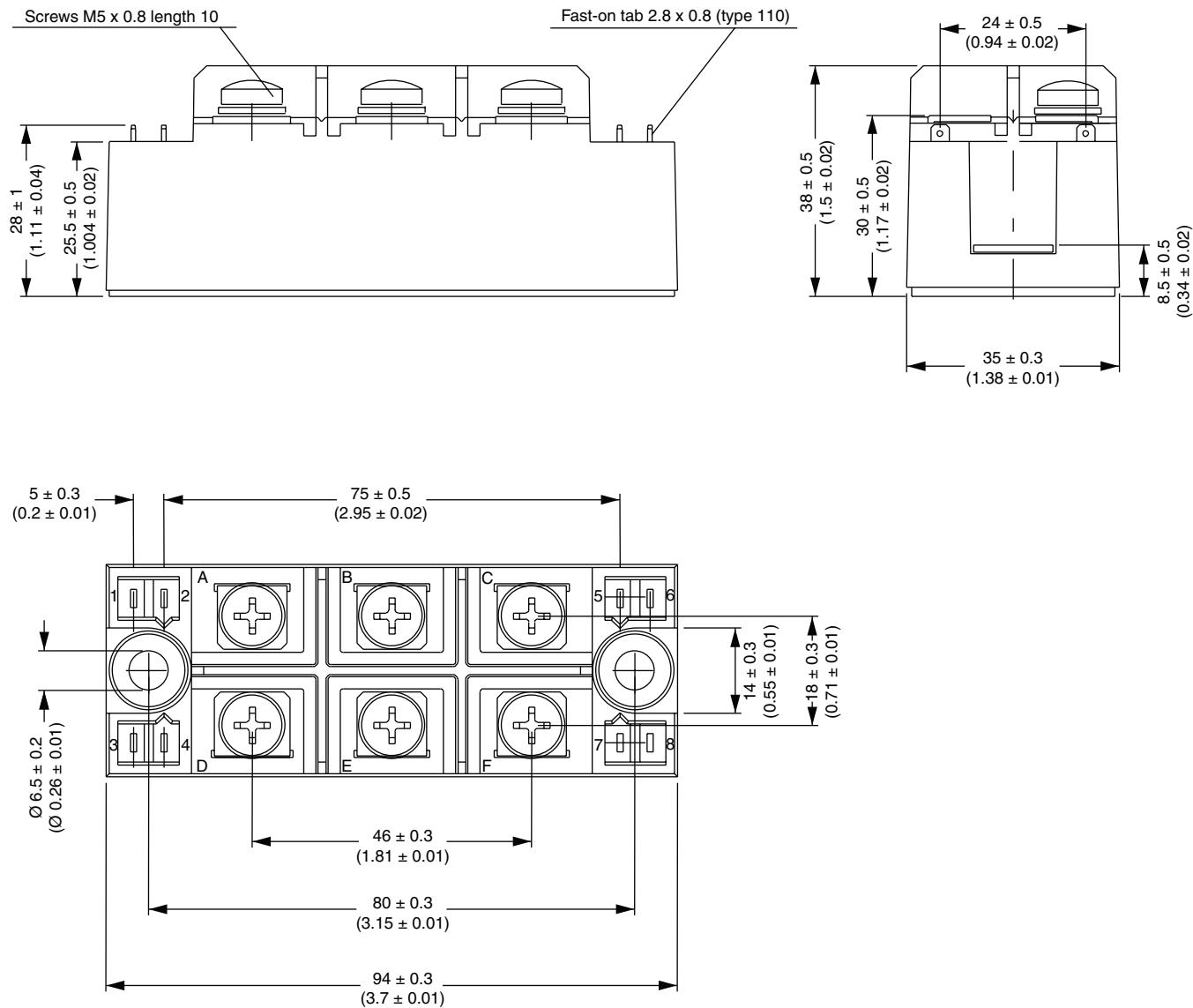
- To order the optional hardware go to [www.vishay.com/doc?95172](http://www.vishay.com/doc?95172)

## CIRCUIT CONFIGURATION



### MTK (with and without optional barrier)

**DIMENSIONS WITH OPTIONAL BARRIERS** in millimeters (inches)



# Outline Dimensions

Vishay High Power Products

MTK  
(with and without optional barrier)



**DIMENSIONS WITHOUT OPTIONAL BARRIERS** in millimeters (inches)

